

# NX3V1G66

## Low-ohmic single-pole single-throw analog switch

Rev. 04 — 8 February 2010

Product data sheet

### 1. General description

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The NX3V1G66 provides one single-pole single-throw analog switch function. It has two input/output terminals (Y and Z) and an active HIGH enable input pin (E). When pin E is LOW, the analog switch is turned off.

Schmitt trigger action at the enable input (E) makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 1.4 V to 4.3 V.

The NX3V1G66 allows signals with amplitude up to  $V_{CC}$  to be transmitted from Y to Z or from Z to Y. Its ultra-low ON resistance (0.3  $\Omega$ ) and flatness (0.1  $\Omega$ ) ensures minimal attenuation and distortion of transmitted signals.

### 2. Features

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- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
  - ◆ 0.8  $\Omega$  (typical) at  $V_{CC} = 1.4$  V
  - ◆ 0.5  $\Omega$  (typical) at  $V_{CC} = 1.65$  V
  - ◆ 0.3  $\Omega$  (typical) at  $V_{CC} = 2.3$  V
  - ◆ 0.25  $\Omega$  (typical) at  $V_{CC} = 2.7$  V
  - ◆ 0.25  $\Omega$  (typical) at  $V_{CC} = 4.3$  V
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114F Class 3A exceeds 7500 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM AEC-Q100-011 revision B exceeds 1000 V
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD78B Class II Level A
- Direct interface with TTL levels at 3.0 V
- Control input accepts voltages above supply voltage
- High current handling capability (500 mA continuous current under 3.3 V supply)
- Specified from  $-40$  °C to  $+85$  °C and from  $-40$  °C to  $+125$  °C

### 3. Applications

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- Cell phone
- PDA
- Portable media player

## 4. Ordering information

Table 1. Ordering information

Type number	Package			Version
	Temperature range	Name	Description	
NX3V1G66GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1
NX3V1G66GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886

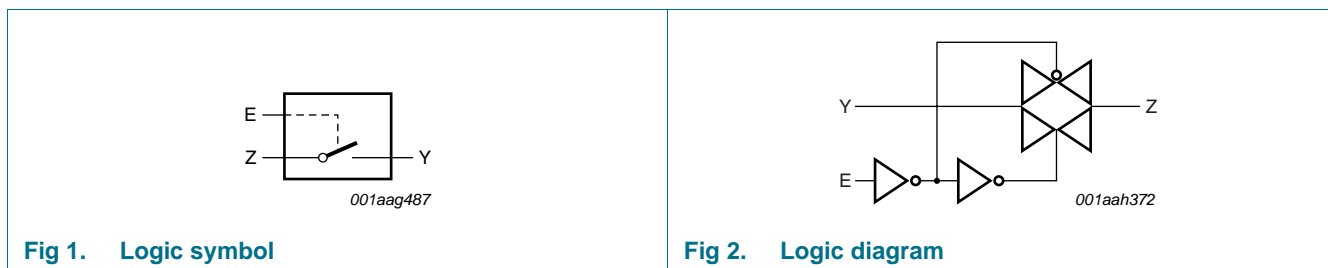
## 5. Marking

Table 2. Marking codes<sup>[1]</sup>

Type number	Marking code
NX3V1G66GW	dL
NX3V1G66GM	dL

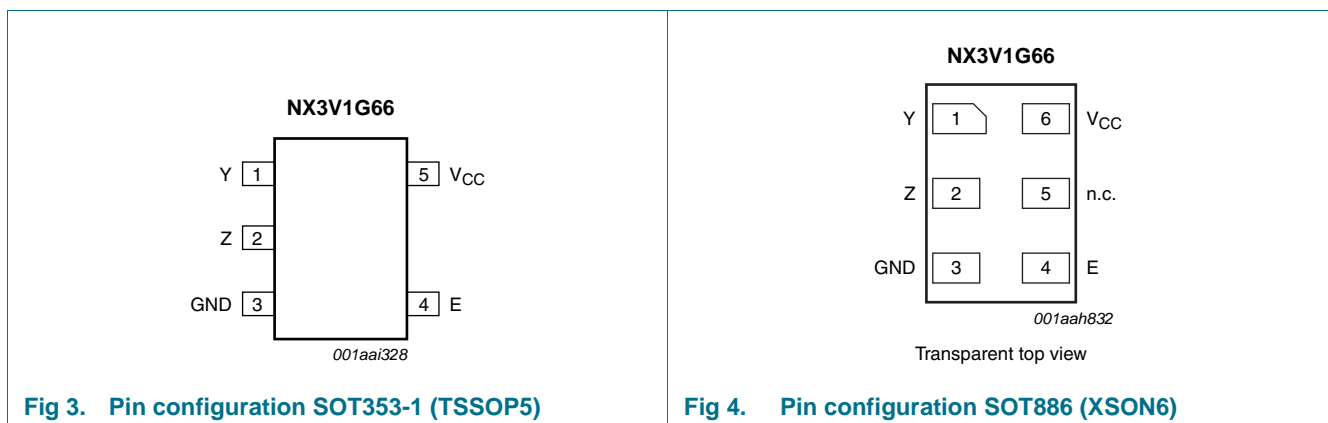
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 6. Functional diagram



## 7. Pinning information

### 7.1 Pinning



## 7.2 Pin description

Table 3. Pin description

Symbol	Pin		Description
	SOT353-1	SOT886	
Y	1	1	independent input or output
Z	2	2	independent output or input
GND	3	3	ground (0 V)
E	4	4	enable input (active HIGH)
n.c.	-	5	not connected
V <sub>CC</sub>	5	6	supply voltage

## 8. Functional description

Table 4. Function table<sup>[1]</sup>

Input E	Switch
L	OFF-state
H	ON-state

[1] H = HIGH voltage level; L = LOW voltage level.

## 9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
V <sub>I</sub>	input voltage	enable input E	<sup>[1]</sup> -0.5	+4.6	V
V <sub>SW</sub>	switch voltage		<sup>[2]</sup> -0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V	-50	-	mA
I <sub>SK</sub>	switch clamping current	V <sub>I</sub> < -0.5 V or V <sub>I</sub> > V <sub>CC</sub> + 0.5 V	-	±50	mA
I <sub>SW</sub>	switch current	V <sub>SW</sub> > -0.5 V or V <sub>SW</sub> < V <sub>CC</sub> + 0.5 V; source or sink current	-	±500	mA
		V <sub>SW</sub> > -0.5 V or V <sub>SW</sub> < V <sub>CC</sub> + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±750	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	<sup>[3]</sup> -	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For TSSOP5 package: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K.  
For XSON6 package: above 118 °C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

## 10. Recommended operating conditions

**Table 6. Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		1.4	4.3	V
$V_I$	input voltage	enable input E	0	4.3	V
$V_{SW}$	switch voltage		[1] 0	$V_{CC}$	V
$T_{amb}$	ambient temperature		-40	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.4\text{ V to }4.3\text{ V}$	[2] -	200	ns/V

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Y. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

## 11. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

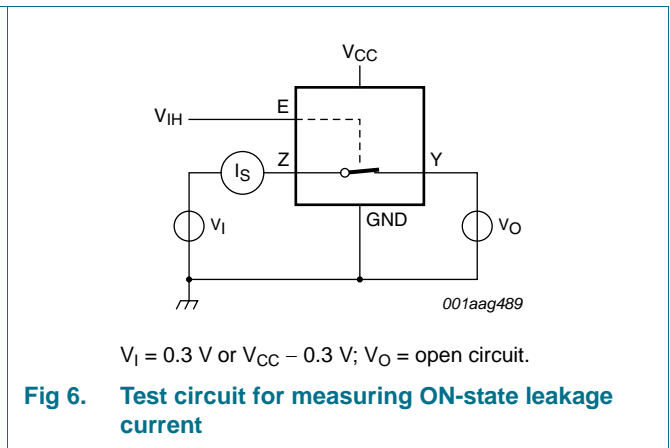
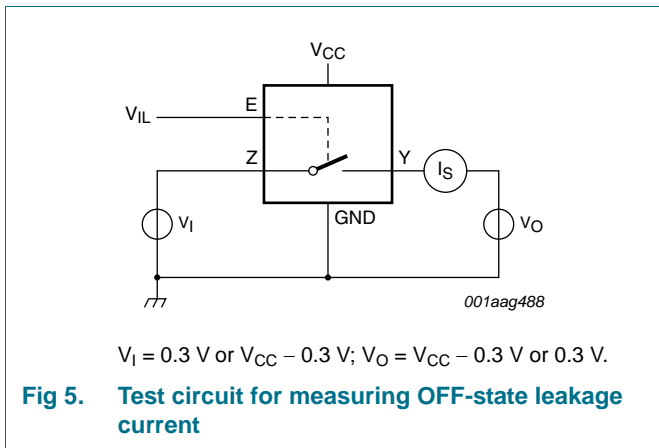
Symbol	Parameter	Conditions	$T_{amb} = 25\text{ °C}$			$T_{amb} = -40\text{ °C to }+125\text{ °C}$			Unit
			Min	Typ	Max	Min	Max (85 °C)	Max (125 °C)	
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 1.4\text{ V to }1.95\text{ V}$	$0.65V_{CC}$	-	-	$0.65V_{CC}$	-	-	V
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	1.7	-	-	1.7	-	-	V
		$V_{CC} = 2.7\text{ V to }3.6\text{ V}$	2.0	-	-	2.0	-	-	V
		$V_{CC} = 3.6\text{ V to }4.3\text{ V}$	$0.7V_{CC}$	-	-	$0.7V_{CC}$	-	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 1.4\text{ V to }1.95\text{ V}$	-	-	$0.35V_{CC}$	-	$0.35V_{CC}$	$0.35V_{CC}$	V
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	-	-	0.7	-	0.7	0.7	V
		$V_{CC} = 2.7\text{ V to }3.6\text{ V}$	-	-	0.8	-	0.8	0.8	V
		$V_{CC} = 3.6\text{ V to }4.3\text{ V}$	-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	$0.3V_{CC}$	V
$I_I$	input leakage current	enable input E; $V_I = \text{GND to }4.3\text{ V};$ $V_{CC} = 1.4\text{ V to }4.3\text{ V}$	-	-	-	-	$\pm 0.5$	$\pm 1$	$\mu\text{A}$
$I_{S(OFF)}$	OFF-state leakage current	Y port; see <a href="#">Figure 5</a>							
		$V_{CC} = 1.4\text{ V to }3.6\text{ V}$	-	-	$\pm 5$	-	$\pm 50$	$\pm 500$	nA
		$V_{CC} = 3.6\text{ V to }4.3\text{ V}$	-	-	$\pm 10$	-	$\pm 50$	$\pm 500$	nA
$I_{S(ON)}$	ON-state leakage current	Z port; see <a href="#">Figure 6</a>							
		$V_{CC} = 1.4\text{ V to }3.6\text{ V}$	-	-	$\pm 5$	-	$\pm 50$	$\pm 500$	nA
		$V_{CC} = 3.6\text{ V to }4.3\text{ V}$	-	-	$\pm 10$	-	$\pm 50$	$\pm 500$	nA
$I_{CC}$	supply current	$V_I = V_{CC}\text{ or GND};$ $V_{SW} = \text{GND or }V_{CC}$							
		$V_{CC} = 3.6\text{ V}$	-	-	100	-	690	6000	nA
		$V_{CC} = 4.3\text{ V}$	-	-	150	-	800	7000	nA

**Table 7. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +125 °C			Unit
			Min	Typ	Max	Min	Max (85 °C)	Max (125 °C)	
C <sub>I</sub>	input capacitance		-	1.0	-	-	-	-	pF
C <sub>S(OFF)</sub>	OFF-state capacitance		-	70	-	-	-	-	pF
C <sub>S(ON)</sub>	ON-state capacitance		-	205	-	-	-	-	pF

### 11.1 Test circuits



### 11.2 ON resistance

**Table 8. Resistance R<sub>ON</sub>**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see [Figure 8](#) to [Figure 14](#).

Symbol	Parameter	Conditions	T <sub>amb</sub> = -40 °C to +85 °C			T <sub>amb</sub> = -40 °C to +125 °C		Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max	
R <sub>ON(peak)</sub>	ON resistance (peak)	V <sub>I</sub> = GND to V <sub>CC</sub> ; I <sub>SW</sub> = 100 mA; see <a href="#">Figure 7</a>						
		V <sub>CC</sub> = 1.4 V	-	0.8	1.9	-	2.1	Ω
		V <sub>CC</sub> = 1.65 V	-	0.5	0.8	-	0.9	Ω
		V <sub>CC</sub> = 2.3 V	-	0.3	0.5	-	0.6	Ω
		V <sub>CC</sub> = 2.7 V	-	0.25	0.45	-	0.5	Ω
		V <sub>CC</sub> = 4.3 V	-	0.25	0.45	-	0.5	Ω

**Table 8. Resistance  $R_{ON}$  ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see [Figure 8](#) to [Figure 14](#).

Symbol	Parameter	Conditions	$T_{amb} = -40\text{ }^{\circ}\text{C to }+85\text{ }^{\circ}\text{C}$			$T_{amb} = -40\text{ }^{\circ}\text{C to }+125\text{ }^{\circ}\text{C}$		Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max	
$R_{ON(flat)}$	ON resistance (flatness)	$V_I = \text{GND to } V_{CC}$ ; $I_{SW} = 100\text{ mA}$						
		$V_{CC} = 1.4\text{ V}$	-	0.5	1.7	-	1.8	$\Omega$
		$V_{CC} = 1.65\text{ V}$	-	0.25	0.6	-	0.7	$\Omega$
		$V_{CC} = 2.3\text{ V}$	-	0.1	0.2	-	0.2	$\Omega$
		$V_{CC} = 2.7\text{ V}$	-	0.1	0.2	-	0.2	$\Omega$
		$V_{CC} = 4.3\text{ V}$	-	0.1	0.25	-	0.25	$\Omega$

[1] Typical values are measured at  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

[2] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical  $V_{CC}$  and temperature.

### 11.3 ON resistance test circuit and graphs

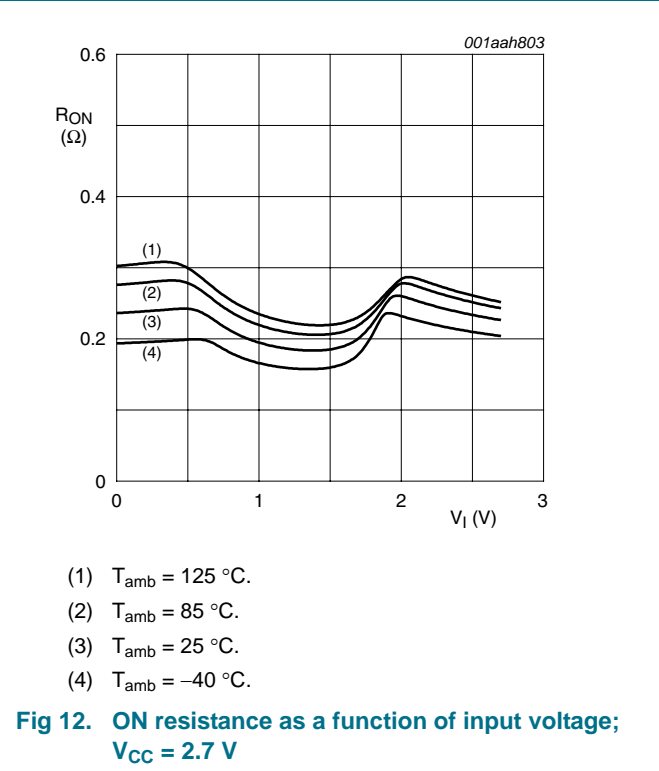
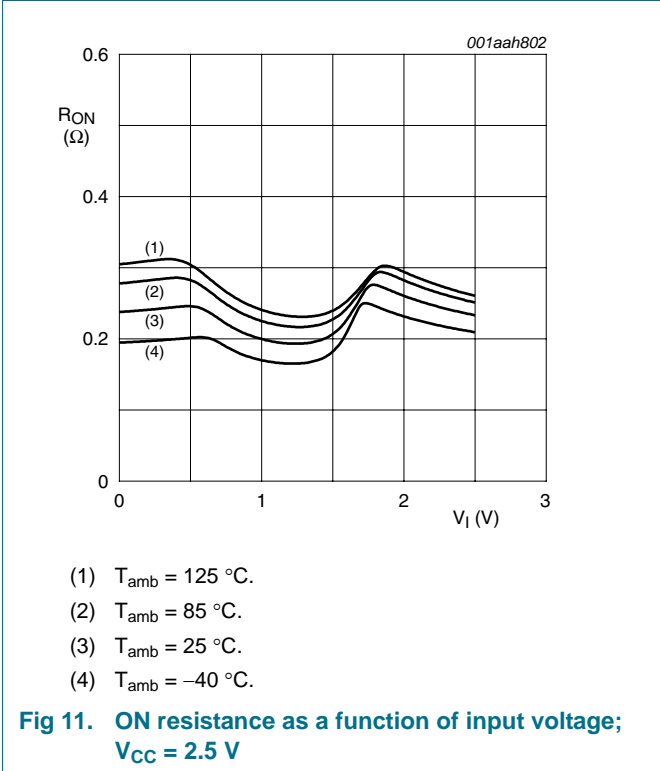
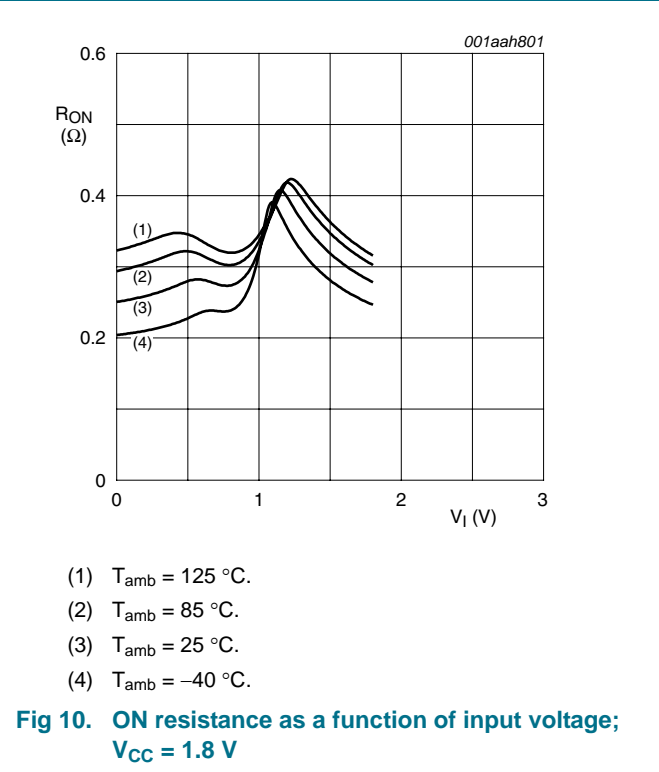
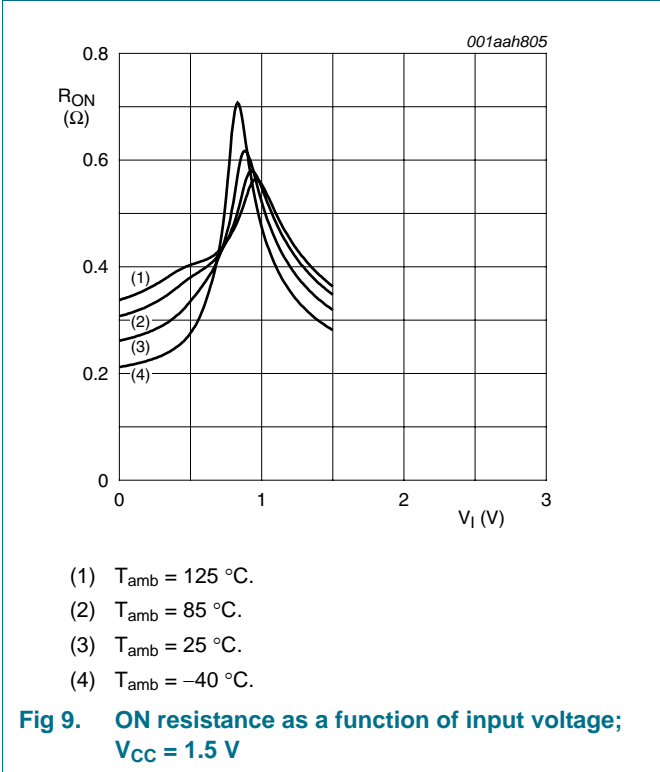
$R_{ON} = V_{SW} / I_{SW}$ .

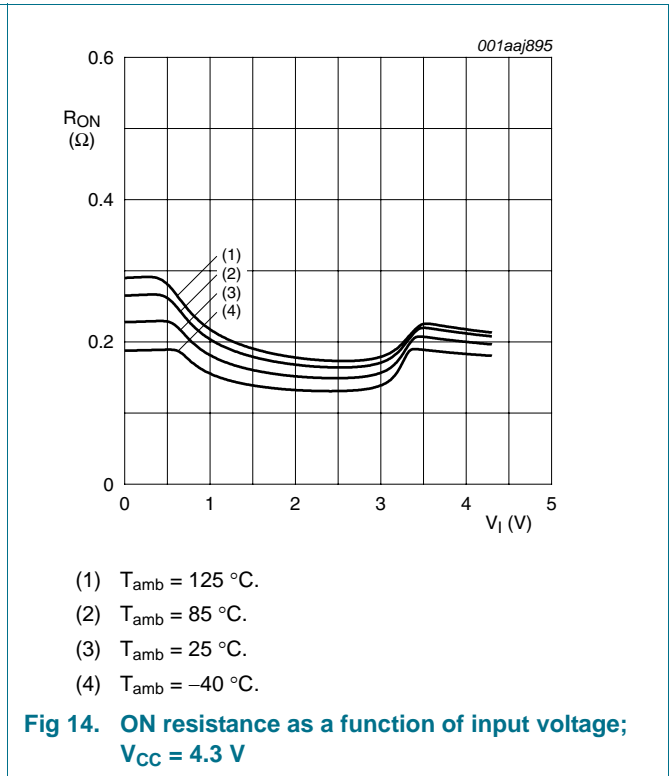
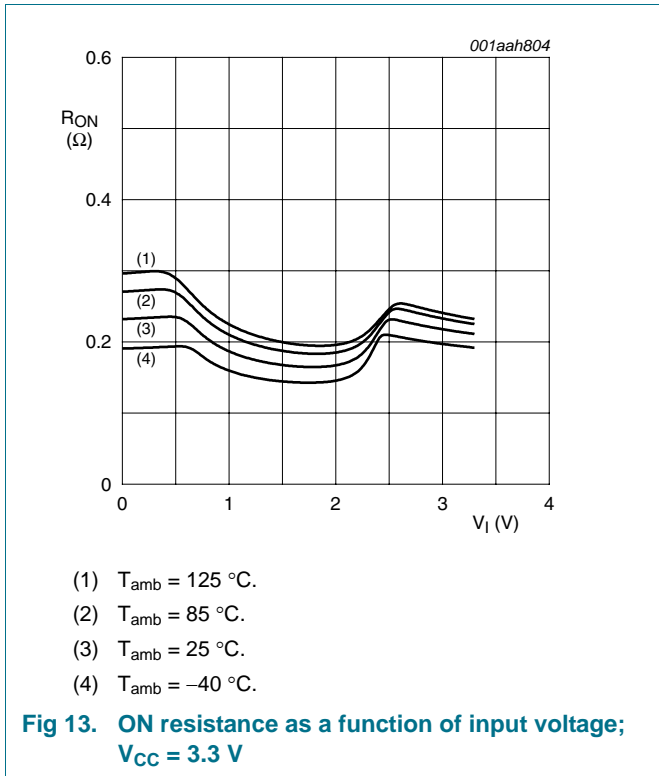
(1)  $V_{CC} = 1.5\text{ V}$ .  
 (2)  $V_{CC} = 1.8\text{ V}$ .  
 (3)  $V_{CC} = 2.5\text{ V}$ .  
 (4)  $V_{CC} = 2.7\text{ V}$ .  
 (5)  $V_{CC} = 3.3\text{ V}$ .  
 (6)  $V_{CC} = 4.3\text{ V}$ .

Measured at  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

**Fig 7. Test circuit for measuring ON resistance**

**Fig 8. Typical ON resistance as a function of input voltage**





## 12. Dynamic characteristics

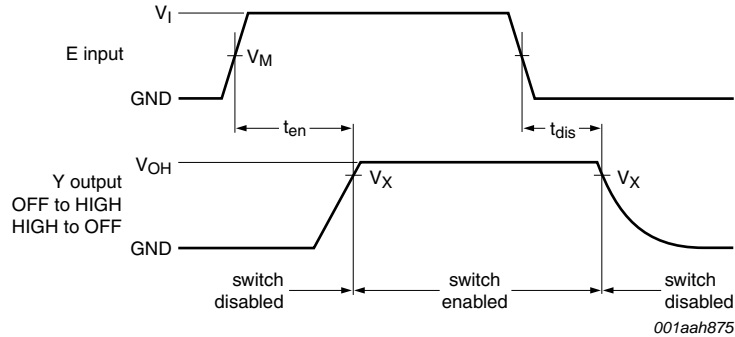
**Table 9. Dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit [Figure 16](#).

Symbol	Parameter	Conditions	$T_{amb} = 25\text{ °C}$			$T_{amb} = -40\text{ °C to }+125\text{ °C}$			Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max (85 °C)	Max (125 °C)	
$t_{en}$	enable time	E to Y; see <a href="#">Figure 15</a>							
		$V_{CC} = 1.4\text{ V to }1.6\text{ V}$	-	28	42	-	45	49	ns
		$V_{CC} = 1.65\text{ V to }1.95\text{ V}$	-	23	35	-	38	41	ns
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	-	17	27	-	29	31	ns
		$V_{CC} = 2.7\text{ V to }3.6\text{ V}$	-	15	24	-	25	28	ns
		$V_{CC} = 3.6\text{ V to }4.3\text{ V}$	-	15	24	-	25	28	ns
$t_{dis}$	disable time	E to Y; see <a href="#">Figure 15</a>							
		$V_{CC} = 1.4\text{ V to }1.6\text{ V}$	-	12	22	-	23	26	ns
		$V_{CC} = 1.65\text{ V to }1.95\text{ V}$	-	9	16	-	17	19	ns
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	-	6	10	-	11	12	ns
		$V_{CC} = 2.7\text{ V to }3.6\text{ V}$	-	5	9	-	10	11	ns
		$V_{CC} = 3.6\text{ V to }4.3\text{ V}$	-	5	9	-	10	11	ns

[1] Typical values are measured at  $T_{amb} = 25\text{ °C}$  and  $V_{CC} = 1.5\text{ V}, 1.8\text{ V}, 2.5\text{ V}, 3.3\text{ V}$  and  $4.3\text{ V}$  respectively.

12.1 Waveform and test circuits

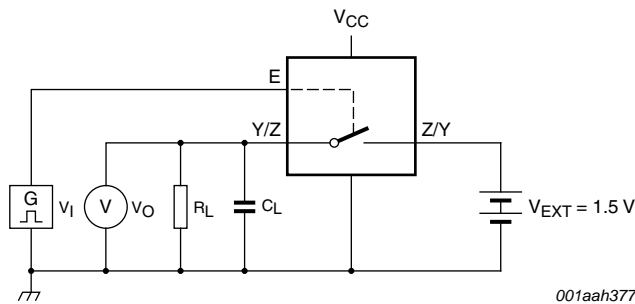


Measurement points are given in [Table 10](#).  
 Logic level:  $V_{OH}$  is the typical output voltage that occurs with the output load.

Fig 15. Enable and disable times

Table 10. Measurement points

Supply voltage	Input	Output
$V_{CC}$	$V_M$	$V_X$
1.4 V to 4.3 V	$0.5V_{CC}$	$0.9V_{OH}$



Test data is given in [Table 11](#).  
 Definitions test circuit:  
 $R_L$  = Load resistance.  
 $C_L$  = Load capacitance including jig and probe capacitance.  
 $V_{EXT}$  = External voltage for measuring switching times.

Fig 16. Load circuit for switching times

Table 11. Test data

Supply voltage	Input	Load
$V_{CC}$	$V_I$	$C_L$ $R_L$
1.4 V to 4.3 V	$V_{CC}$	$\leq 2.5$ ns      35 pF      50 $\Omega$

12.2 Additional dynamic characteristics

Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = GND$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \leq 2.5$  ns;  $T_{amb} = 25$  °C.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
THD	total harmonic distortion	$f_i = 20$ Hz to 20 kHz; $R_L = 32$ $\Omega$ ; see <a href="#">Figure 17</a>	[1]			
		$V_{CC} = 1.4$ V; $V_I = 1$ V (p-p)	-	0.05	-	%
		$V_{CC} = 1.65$ V; $V_I = 1.2$ V (p-p)	-	0.03	-	%
		$V_{CC} = 2.3$ V; $V_I = 1.5$ V (p-p)	-	0.01	-	%
		$V_{CC} = 2.7$ V; $V_I = 2$ V (p-p)	-	0.01	-	%
		$V_{CC} = 4.3$ V; $V_I = 2$ V (p-p)	-	0.01	-	%
$f_{(-3dB)}$	-3 dB frequency response	$R_L = 50$ $\Omega$ ; see <a href="#">Figure 18</a>	[1]			
		$V_{CC} = 1.4$ V to 4.3 V	-	25	-	MHz
$\alpha_{iso}$	isolation (OFF-state)	$f_i = 100$ kHz; $R_L = 50$ $\Omega$ ; see <a href="#">Figure 19</a>	[1]			
		$V_{CC} = 1.4$ V to 4.3 V	-	-90	-	dB
$V_{ct}$	crosstalk voltage	between digital input and switch;				
		$f_i = 1$ MHz; $C_L = 50$ pF; $R_L = 50$ $\Omega$ ; see <a href="#">Figure 20</a>				
		$V_{CC} = 1.4$ V to 3.6 V	-	0.3	-	V
		$V_{CC} = 3.6$ V to 4.3 V	-	0.5	-	V
$Q_{inj}$	charge injection	$f_i = 1$ MHz; $C_L = 0.1$ nF; $R_L = 1$ M $\Omega$ ; $V_{gen} = 0$ V; $R_{gen} = 0$ $\Omega$ ; see <a href="#">Figure 21</a>				
		$V_{CC} = 1.5$ V	-	6.5	-	pC
		$V_{CC} = 1.8$ V	-	6.5	-	pC
		$V_{CC} = 2.5$ V	-	6.5	-	pC
		$V_{CC} = 3.3$ V	-	6.5	-	pC
		$V_{CC} = 4.3$ V	-	12	-	pC

[1]  $f_i$  is biased at  $0.5V_{CC}$ .

12.3 Test circuits

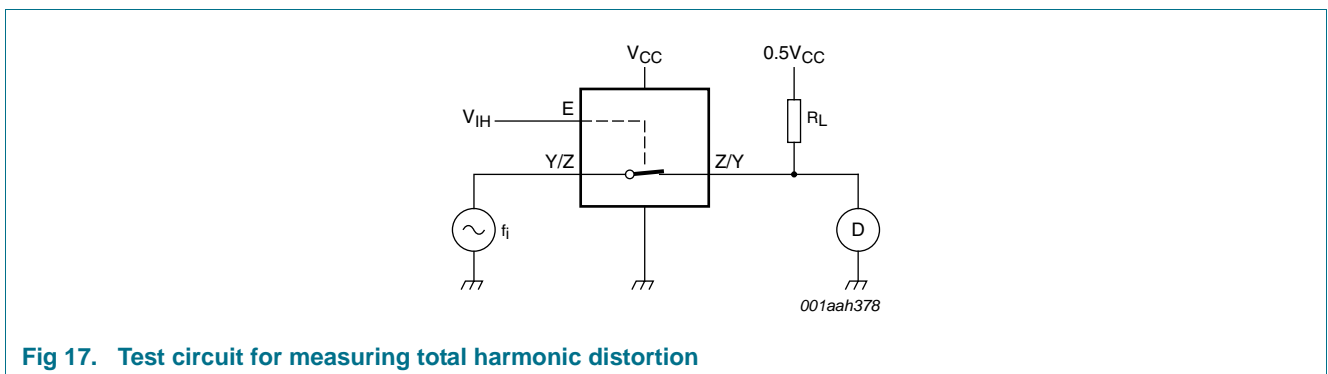
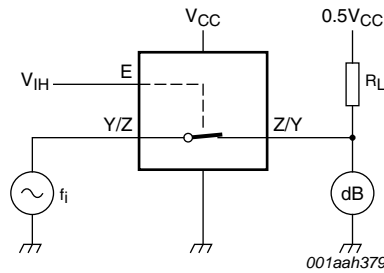
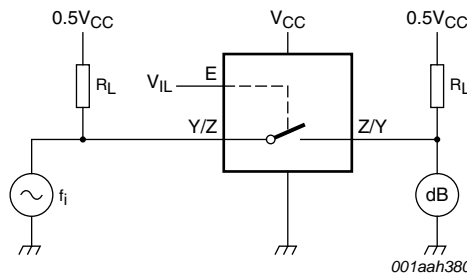


Fig 17. Test circuit for measuring total harmonic distortion



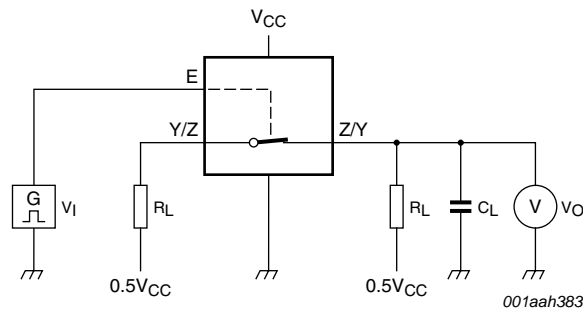
Adjust  $f_i$  voltage to obtain 0 dBm level at output. Increase  $f_i$  frequency until dB meter reads  $-3$  dB.

**Fig 18. Test circuit for measuring the frequency response when switch is in ON-state**

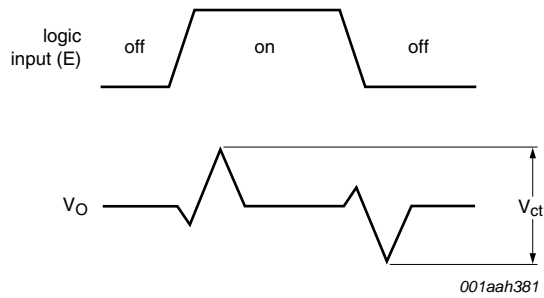


Adjust  $f_i$  voltage to obtain 0 dBm level at input.

**Fig 19. Test circuit for measuring isolation (OFF-state)**

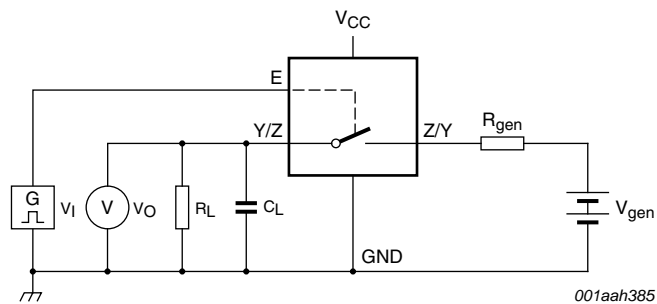


a. Test circuit

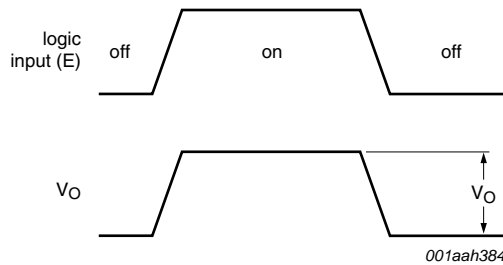


b. Input and output pulse definitions

**Fig 20. Test circuit for measuring crosstalk voltage between digital input and switch**



a. Test circuit.



b. Input and output pulse definitions.

Definition:  $Q_{inj} = \Delta V_O \times C_L$ .

$\Delta V_O$  = output voltage variation.

$R_{gen}$  = generator resistance.

$V_{gen}$  = generator voltage.

**Fig 21. Test circuit for measuring charge injection**

13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1

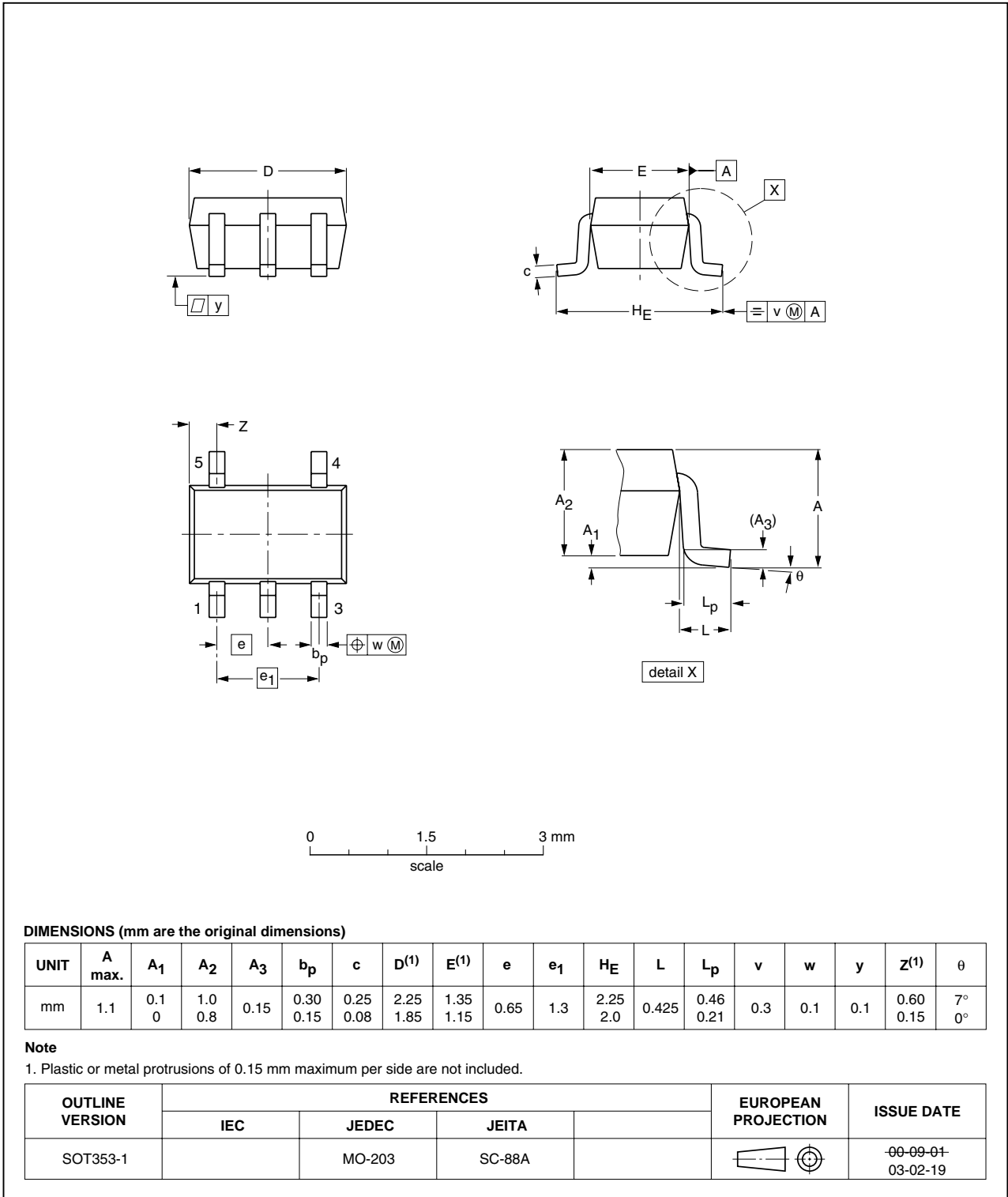


Fig 22. Package outline SOT353-1 (TSSOP5)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

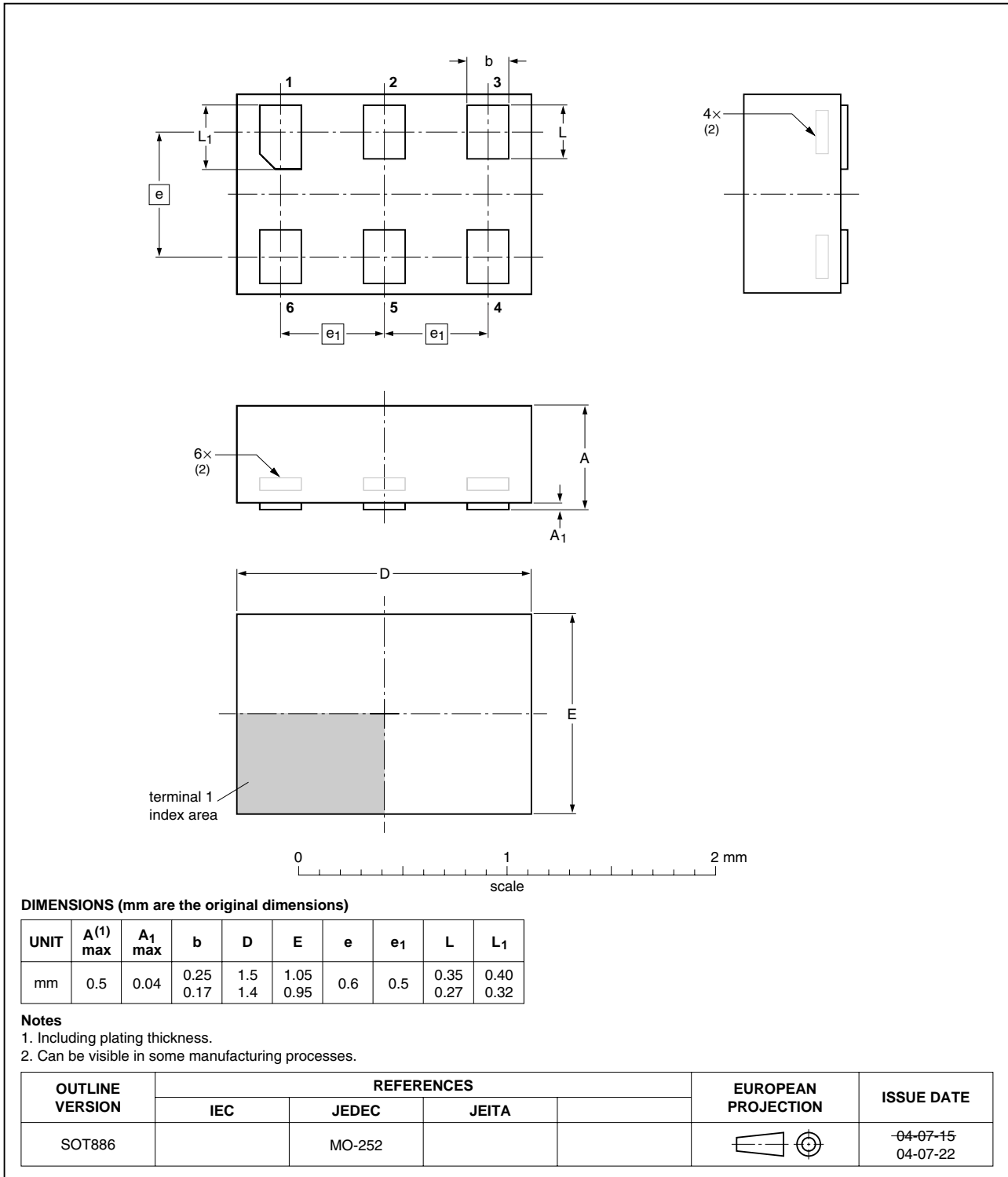


Fig 23. Package outline SOT886 (XSON6)

## 14. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
PDA	Personal Digital Assistant
TTL	Transistor-Transistor Logic

## 15. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3V1G66_4	20100208	Product data sheet	-	NX3V1G66_3
Modifications:	<ul style="list-style-type: none"> <li>• <a href="#">Figure 5</a>: Test circuit drawing has changed.</li> <li>• <a href="#">Table 8</a>: ON resistance (flatness) changed at <math>V_{CC} = 4.3</math> V.</li> </ul>			
NX3V1G66_3	20090409	Product data sheet	-	NX3V1G66_2
NX3V1G66_2	20080728	Product data sheet	-	NX3V1G66_1
NX3V1G66_1	20080421	Product data sheet	-	-

## 16. Legal information

### 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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